

Subminiature Photoelectric Sensor

E3T

Omron's Next Generation of Miniature Photoelectric Sensors

- Utilizes Omron's "Hyper LED" technology to achieve the industry's smallest visible red beam
- Self-contained sensor ideal for compact applications
- "Pin-point" beam for detecting extremely small objects
- Offered in both flat and rectangular body styles
- Retroreflective model employs Omron's Free-Angle Optics technology (FAO) to detect objects as small as 2 mm dia
- Convergent-beam model spot diameter is 0.15 mm
- Through-beam model is capable of sensing distances of 1 meter with a 2 mm target diameter
- CE conformance





Ordering Information

■ PHOTOELECTRIC SENSORS

Sensor type		Sensing method								
			Through-beam		Retroreflective	Diffuse reflective	ive Convergent-beam			
Appearance			Side-view	Flat	Side-view	Flat	Side-view			
			There							
Sensing distan	ce		1 m	500 mm	10 to 200 mm	5 to 30 mm	5 to 15 mm	5 to 30 mm		
Part number	Light-ON	NPN	E3T-ST11	E3T-FT11	E3T-SR11	E3T-FD11N	E3T-SL11	E3T-SL21		
		PNP	E3T-ST13	E3T-FT13	E3T-SR13	E3T-FD13N	E3T-SL13	E3T-SL23		
	Dark-ON	NPN	E3T-ST12	E3T-FT12	E3T-SR12	E3T-FD12N	E3T-SL12	E3T-SL22		
		PNP	E3T-ST14	E3T-FT14	E3T-SR14	E3T-FD14N	E3T-SL14	E3T-SL24		

Note: All through-beam models are packaged and sold as pairs (one transmitter and one receiver).

■ ACCESSORIES (ORDER SEPARATELY)

Slits (Apertures)

Slits for sensor models	Slit width	Sensing distance	Minimum sensing object (typical)	Comments	Part number
E3T-ST1□	0.5 dia.	50 mm	0.5 mm wide	One each for Emitter	E39-S63
	1 dia.	100 mm	1 mm wide	and Receiver	

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	1 dia.	100 mm	1 mm wide	and Receiver	

Reflectors

Item	Sensing distance	Minimum sensing object (typical)	Part number
Compact retroreflective model	10 to 200 mm	2 mm wide	E39-R4 (See Note.)
	10 to 100 mm		E39-R37

Note: E39-R4 reflector included with the E3T-SR1 \square (can also be ordered separately).

Adjustable Aperture

For sensor models	Appearance	Part number
E3T-ST1□		E39-E10

Mounting Brackets

For sensor models	Appearance	Comments	Part number
E3T-S□		Two mounting brackets are required for through-beam models.	E39-L116
			E39-L117
			E39-L118
E3T-F□			E39-L119
			E39-L120

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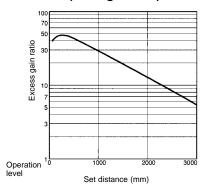
■ RATINGS/CHARACTERISTICS

Sensing method		Through-beam			Retroreflective Convergent beam			Diffuse reflective					
Shape		Side-view Flat			Side-vie	Side-view					Flat		
Output type	·		PNP	NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP
Part number	Light-ON	-ST11	-ST13	-FT11	-FT13	-SR11	-SR13	-SL11	-SL13	-SL21	-SL23	-FD11N	-FD13N
	Dark-ON	-ST12	-ST14	-FT12	-FT14	-SR12	-SR14	-SL12	-SL14	-SL22	-SL24	-FD12N	-FD14N
Sensing dista	nce	1 m (adjusta apertur availab	e is	500 mm	1	10 to 20 (with the	0 mm E39-R4)	5 to 15 (50 x 5 Kodak card)	0 mm	5 to 30 (50 x 5 Kodak card)	0 mm	5 to 30 m (50 x 50 Kodak w	
Standard sens	sing target	2 mm c	lia. min.			10 mm c	dia. min.						
Min. sensing t (typical)	arget	2 mm c	lia. min.			2 mm dia (sensing at 100 m	distance	0.15 m	m dia. (s	ensing d	istance a	at 10 mm)	
Differential tra	vel							2 mm r	max.	6 mm r	nax.	6 mm ma	ax.
Optical	Emitter	3° to 10)°	3° to 13	S °	2° to 5°							
angle	Receiver	3° to 70)°	3° to 70	0								
Light source (wave length)		Red LE	D ("Pin-ן	point" LE	D) (λ=670	0 nm)							
Power supply	voltage	12 to 2	4 VDC ±	10%, ripp	ole (p-p) 1	0% max.							24 VDC ±10%
Current consu	ımption	12 mA	max. em	itter/rece	eiver	20 mA n	nax.						l .
Output		Open collector, load current: 50 mA max. at 24 VDC, residual voltage: 1 V max., operation mode: Light-ON or Dark-ON (separate models)											
Circuit protection (See Precautions Section.)		Protection from reversed and output short-circuit Protection from reversed polarity, output short-circuit, and mutual interference							al				
Response tim	е	1 ms max. each for on and off											
Ambient light	Incandes- cent lamp	5,000 ℓx max.											
immunity	Sunlight	10,000	ℓx max.										
Ambient	Operating	−25°C	to 55°C (–13°F to	131°F)								
temperature	Storage	-40°C ¹	to 70°C (–40°F to	158°F) w	ith no icin	g or conde	ensation					
Ambient	Operating	35% to	85% R⊦										
humidity	Storage	35% to	95% RF	(with no	condens	ation)							
Insulation res	stance	20 MΩ min. (at 500 VDC)											
Dielectric stre	ngth	1,000 VAC, 50/60 Hz for 1 min											
Vibration resis	stance	10 to 2,000 Hz, 1.5-mm double amplitude or 300 m/s ² (approx. 30G) for 0.5 hrs each in X, Y, and Z axis											
Shock resistance		1,000 m/s ² (approx. 100G) 3 times each in X, Y, and Z axis											
Enclosure rating		IEC605	29: IP67										
Connection method		Pre-leaded (standard length: 2 m)											
Weight (with packaging)		Approx. 40 g Approx. 20 g											
Materials	Case	PBT											
	Lens and cover	Polycarbonate											
Accessories in	ncluded	Two ea		! mountin	g screws	, spring w	ashers, an	d flat wa	shers, a	nd reflect	tor (E39-	R4: retrore	eflective

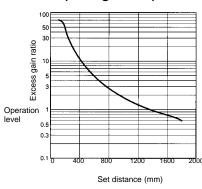
Engineering Data

■ EXCESS GAIN VS. SET DISTANCE (TYPICAL)

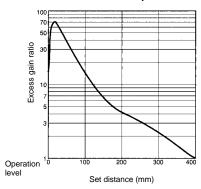
E3T-ST1□ (Through-beam)



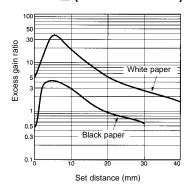
E3T-FT1 ☐ (Through-beam)



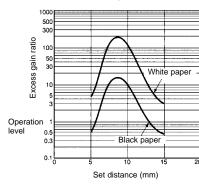
E3T-SR1 with E39-R4 (Retroreflective)



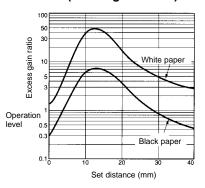
E3T-FD1 (Diffuse Reflective)



E3T-SL1 (Convergent Beam)

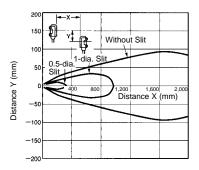


E3T-SL2□ (Convergent Beam)

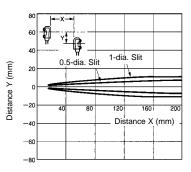


■ PARALLEL OPERATING RANGE (TYPICAL)

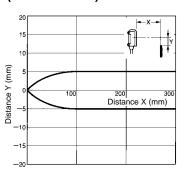
E3T-ST1□ with Slit (Aperture) (Through-beam)



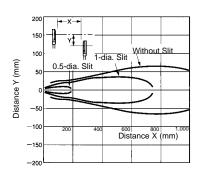
E3T-ST1□ with Slit (Enlarged graph) (Through-beam)



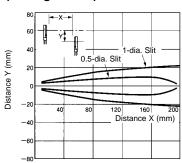
E3T-SR1 with E39-R4 (Retroreflective)



E3T-FT1 with Slit (Through-beam)



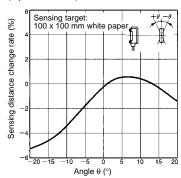
E3T-FT1□ with Slit (Enlarged graph) (Through-beam)



■ ANGLE CHARACTERISTICS (TYPICAL)

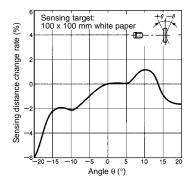
E3T-SL1□

(Up and Down)



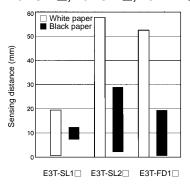
E3T-SL1□

(Left and Right)



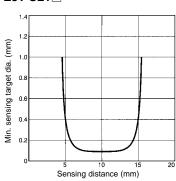
■ CLOSE-DISTANCE SENSING CAPABILITY (TYPICAL)

E3T-SL1 , E3T-SL2 , E3T-FD1

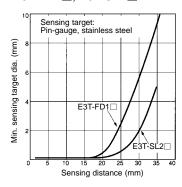


■ SENSING TARGET SIZE VS. SENSING DISTANCE (TYPICAL)

E3T-SL1□

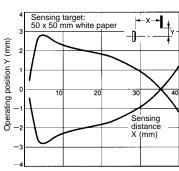


E3T-FD1□, E3T-SL2□

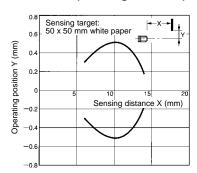


■ OPERATION RANGE (TYPICAL)

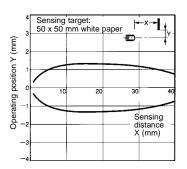
E3T-FD1 (Diffuse Reflective)



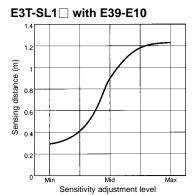
E3T-SL1 (Convergent Beam)



E3T-SL2□ (Convergent Beam)

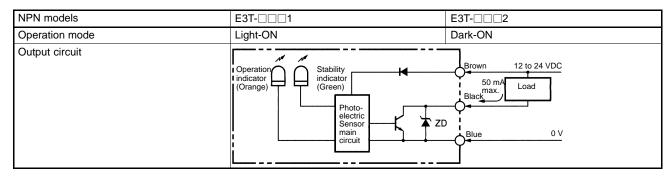


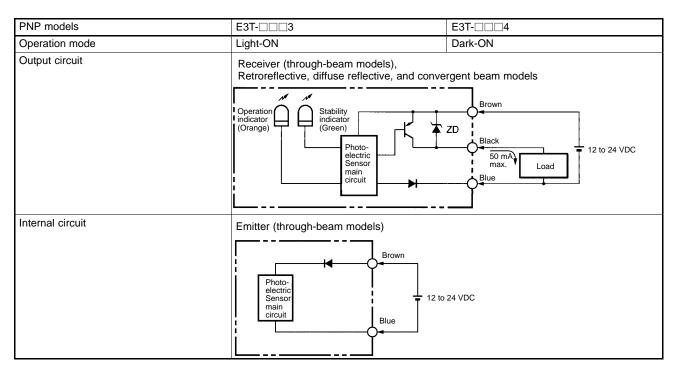
■ SENSING DISTANCE CHARACTERISTICS OF ADJUSTABLE APERTURE (WHEN COMPLETING OPTICAL AXIS ADJUSTMENT)



Operation

■ OUTPUT CIRCUITS





■ TIMING CHART

Diffuse and convergent beam	Light-ON	Dark-ON		
	Target present	Target present		
	Target not present	Target not present		
	Operation ON indicator (orange) OFF	Operation ON indicator (orange) OFF		
	Output transistor OFF	Output ON transistor OFF		
	Load Energized De-energized	Load De-energized De-energized		
Retroreflective/through-beam	Light-ON	Dark-ON		
	Target present	Target present		
	Target not present	Target not present		
	Operation ON indicator (orange) OFF	Operation ON indicator (orange) OFF		
	Output transistor OFF	Output ON transistor OFF		
	Load Energized De-energized	Energized Load De-energized		

Dimensions

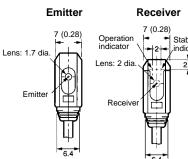
Unit: mm (inch)

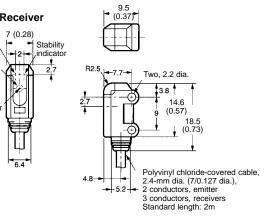
■ SIDE-VIEW SENSORS

(Through-beam Models)

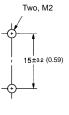
E3T-ST11 E3T-ST12 E3T-ST13 E3T-ST14







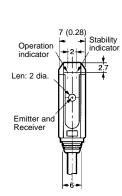


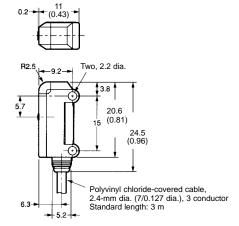


Retroreflective Models

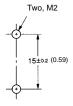
E3T-SR11 E3T-SR12 E3T-SR13 E3T-SR14







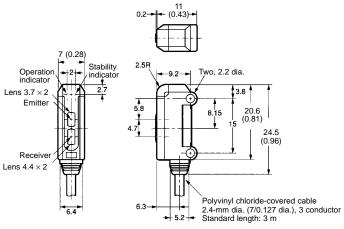
Mounting Holes



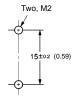
Convergent-beam Models

E3T-SL11	E3T-SL21
E3T-SL12	E3T-SL22
E3T-SL13	E3T-SL23
E3T-SL14	E3T-SL24









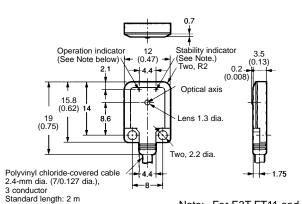
Unit: mm (inch)

■ FLAT THIN SENSORS

Through-beam Emitter and Receiver Models

E3T-FT11 E3T-FT12 E3T-FT13 E3T-FT14





Mounting Holes

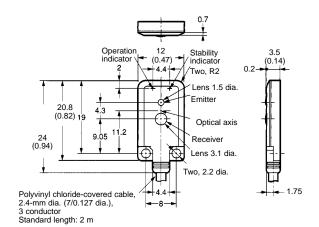
Two, M2

Note: For E3T-FT11 and E3T-FT12 Receivers only.

Diffuse Reflective Models

E3T-FD11-N E3T-FD12-N E3T-FD13-N E3T-FD14-N









■ REFLECTORS

Retroreflector

E39-R4 (Provided with the E3T-SR1□)



